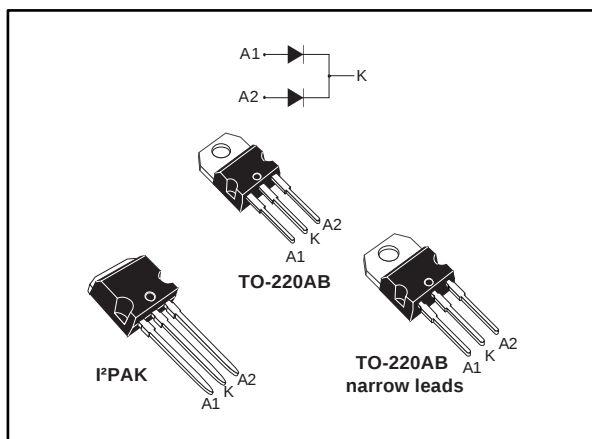


Power Schottky rectifier

Datasheet - production data



Features

- High current capability
- Avalanche rated
- Low forward voltage drop current
- High frequency operation
- ECOPACK®2 compliant component on TO-220AB

Description

This Schottky rectifier is suited for high frequency switch mode power supply.

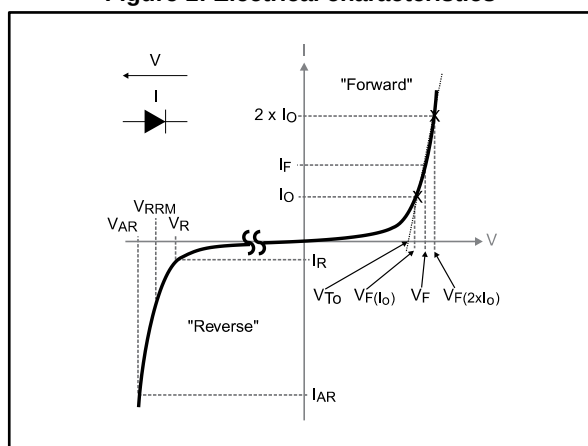
The voltage drop versus leakage current trade-off is in keeping with medium power hi-density adapter design.

Packaged in TO-220AB narrow leads, TO-220AB and I²PAK, this device is intended to be used in notebook, game station and desktop adaptors, providing in these applications a good efficiency at both low and high load.

Table 1: Device summary

Symbol	Value
$I_{F(AV)}$	2 x 20 A
V_{RRM}	120 V
$T_j(max.)$	150 °C
$V_F(typ.)$	0.46 V

Figure 1: Electrical characteristics



V_{ARM} and I_{ARM} must respect the reverse safe operating area defined in Figure 9. V_{AR} and I_{AR} are pulse measurements ($t_p < 1 \mu s$). V_R , I_R , V_{RRM} and V_F , are static characteristics.

1 Characteristics

Table 2: Absolute ratings (per diode, limiting values at 25 °C, unless otherwise specified)

Symbol	Parameter		Value	Unit
V _{RRM}	Repetitive peak reverse voltage		120	V
I _{F(RMS)}	Forward rms current		30	A
I _{F(AV)}	Average forward current δ = 0.5, square wave	Per diode, T _C = 125 °C	20	A
		Per device, T _C = 115 °C	40	
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms sine-wave	210	A
P _{ARM} ⁽¹⁾	Repetitive peak avalanche power	t _p = 10 μs, T _J = 125 °C	1150	W
V _{ARM} ⁽²⁾	Maximum repetitive peak avalanche voltage	t _p < 10 μs, T _J < 125 °C, I _{AR} < 7.7 A	150	V
V _{ASM}	Maximum single pulse peak avalanche voltage			
T _{stg}	Storage temperature range		-65 to +175	°C
T _J	Maximum operating junction temperature ⁽³⁾		150	°C

Notes:

⁽¹⁾For pulse time duration deratings, please refer to figure 4. More details regarding the avalanche energy measurements and diode validation in the avalanche are provided in the application notes AN1768 and AN2025.

⁽²⁾See Figure 9

⁽³⁾ $(dP_{tot}/dT_j) < (1/R_{th(j-a)})$ condition to avoid thermal runaway for a diode on its own heatsink.

Table 3: Thermal parameters

Symbol	Parameter		Max. value	Unit
$R_{th(j-c)}$	Junction to case	Per diode	1.35	°C/W
		Total	0.93	
$R_{th(c)}$	Coupling		0.50	

When the two diodes 1 and 2 are used simultaneously:

$$\Delta T_j(\text{diode } 1) = P(\text{diode } 1) \times R_{th(j-c)}(\text{Per diode}) + P(\text{diode } 2) \times R_{th(c)}$$

Table 4: Static electrical characteristics (values per diode)

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
$I_R^{(1)}$	Reverse leakage current	$T_J = 25\text{ }^{\circ}\text{C}$	$V_R = V_{RRM}$	-	55	275	μA
		$T_J = 125\text{ }^{\circ}\text{C}$		-	20	50	mA
$V_F^{(2)}$	Forward voltage drop	$T_J = 125\text{ }^{\circ}\text{C}$	$I_F = 5\text{ A}$	-	0.46	0.51	V
		$T_J = 125\text{ }^{\circ}\text{C}$	$I_F = 10\text{ A}$	-	0.55	0.60	
		$T_J = 25\text{ }^{\circ}\text{C}$	$I_F = 20\text{ A}$	-		0.83	
		$T_J = 125\text{ }^{\circ}\text{C}$		-	0.63	0.69	

Notes:⁽¹⁾Pulse test: $t_p = 5\text{ ms}$, $\delta < 2\%$ ⁽²⁾Pulse test: $t_p = 380\text{ }\mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses, use the following equation:

$$P = 0.52 \times I_{F(AV)} + 0.0085 \times I_{F(RMS)}^2$$

1.1 Characteristics (curves)

Figure 2: Average forward power dissipation versus average forward current (per diode)

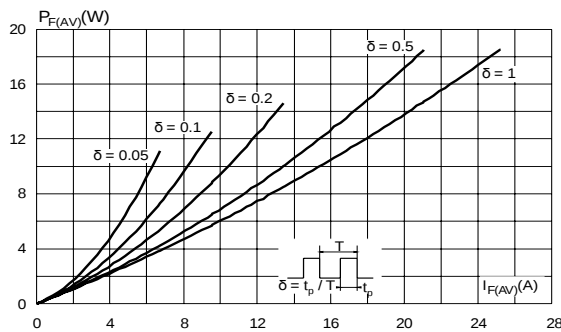


Figure 3: Average forward current versus ambient temperature ($\delta = 0.5$, per diode)

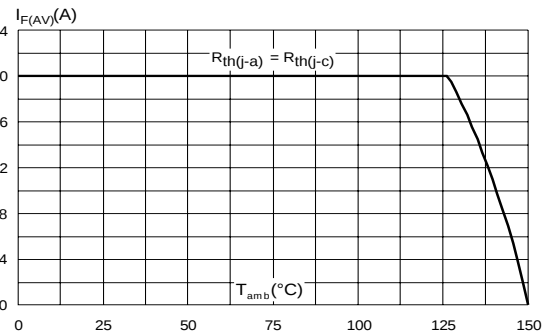


Figure 4: Normalized avalanche power derating versus pulse duration (per diode)

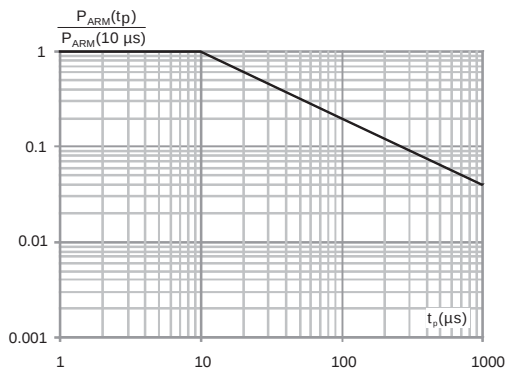


Figure 5: Relative variation of thermal impedance junction to case versus pulse duration (per diode)

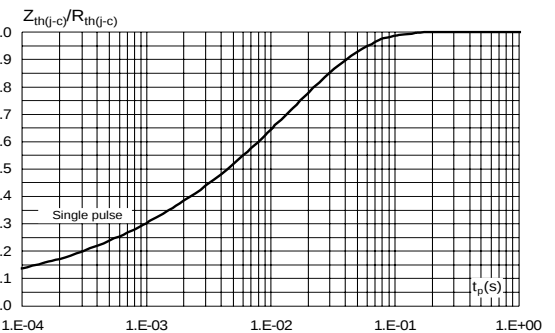


Figure 6: Reverse leakage current versus reverse voltage applied (typical values, per diode)

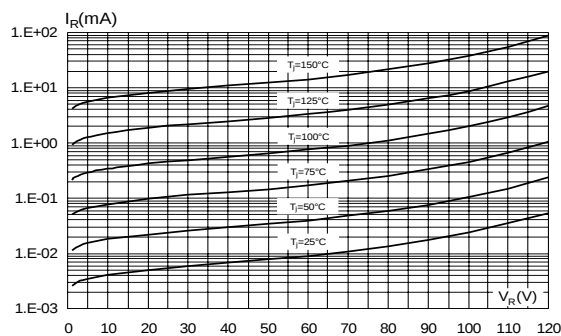


Figure 7: Junction capacitance versus reverse voltage applied (typical values, per diode)

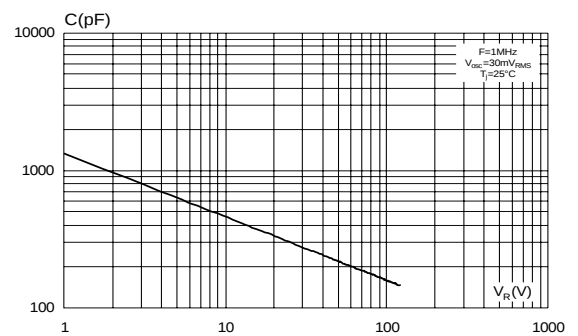
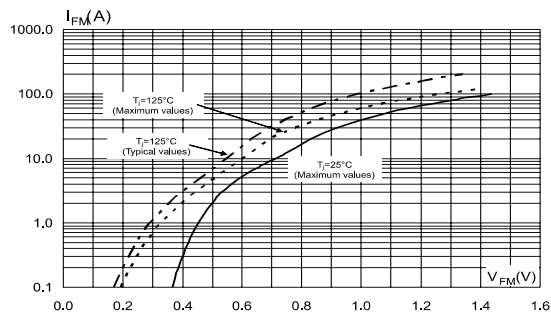
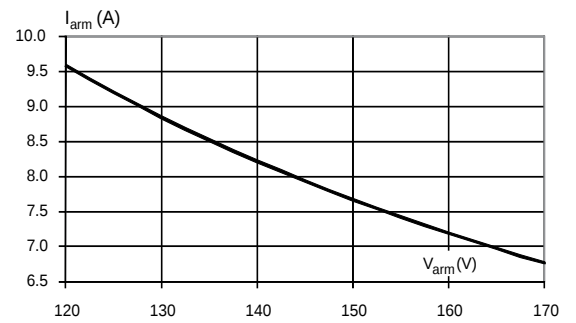


Figure 8: Forward voltage drop versus forward current (per diode)**Figure 9: Reverse safe operating area ($t_p < 1 \mu\text{s}$ and $T_j < 150^\circ\text{C}$, per diode)**

2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

- Cooling method: by conduction (C)
- Epoxy meets UL 94,V0
- Recommended torque value: 0.55 N·m (for TO-220AB)
- Maximum torque value: 0.7 N·m (for TO-220AB)

2.1 TO-220AB narrow leads package information

Figure 10: TO-220AB narrow leads package outline

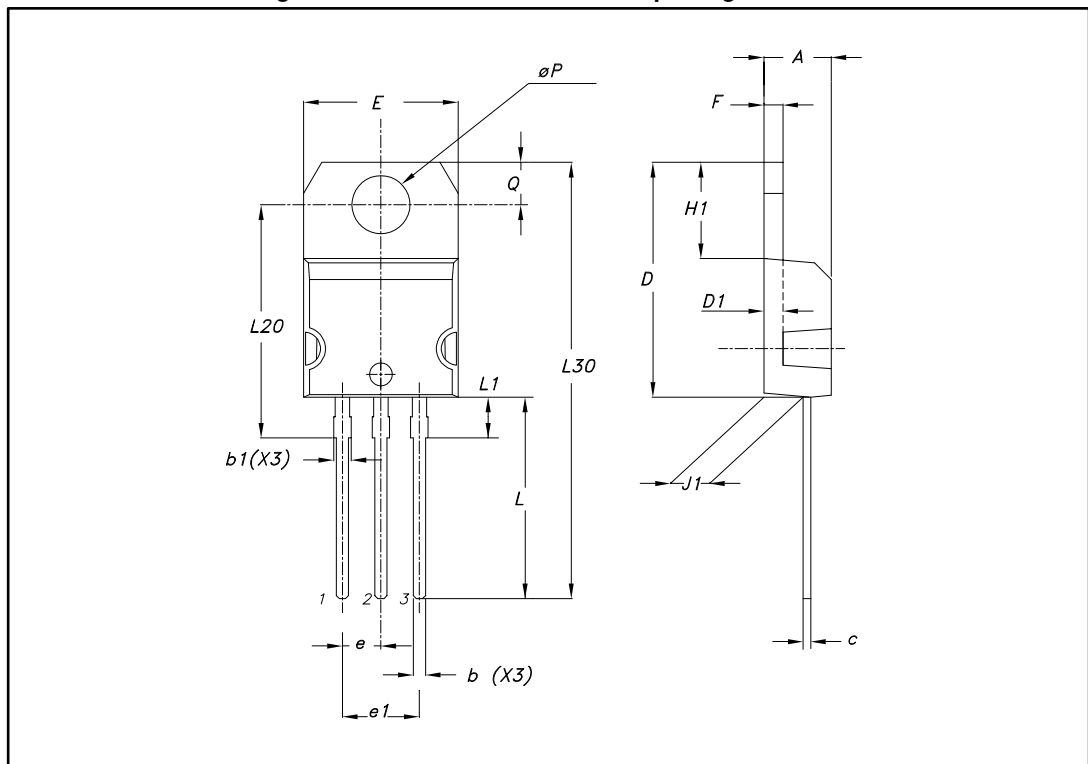


Table 5: TO-220AB narrow leads package mechanical data

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.17	0.18
b	0.61	0.88	0.024	0.034
b1	0.95	1.20	0.037	0.047
c	0.48	0.70	0.019	0.027
D	15.25	15.75	0.060	0.062
D1	1.27 typ.		0.05 typ.	
E	10.00	10.40	0.39	0.41
e	2.40	2.70	0.094	0.106
e1	4.95	5.15	0.19	0.20
F	1.23	1.32	0.048	0.052
H1	6.20	6.60	0.24	0.26
J1	2.40	2.72	0.095	0.107
L	13.00	14.00	0.51	0.55
L1	2.60	2.90	0.102	0.114
L20	15.40 typ.		0.61	
L30	28.90 typ.		1.14	
ØP	3.75	3.85	0.147	0.151
Q	2.65	2.95	0.104	0.116

2.2 TO-220AB package information

Figure 11: TO-220AB package outline

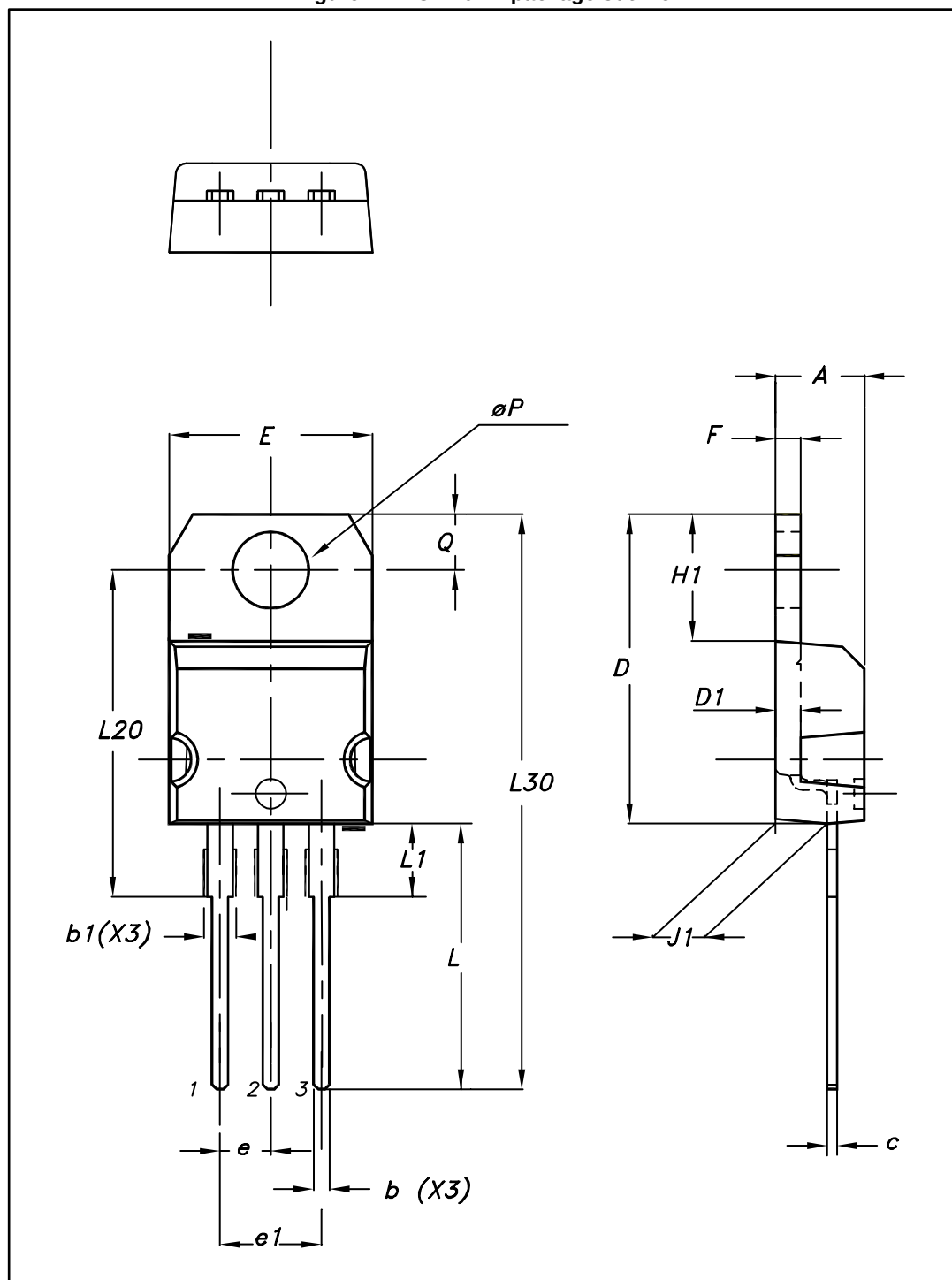
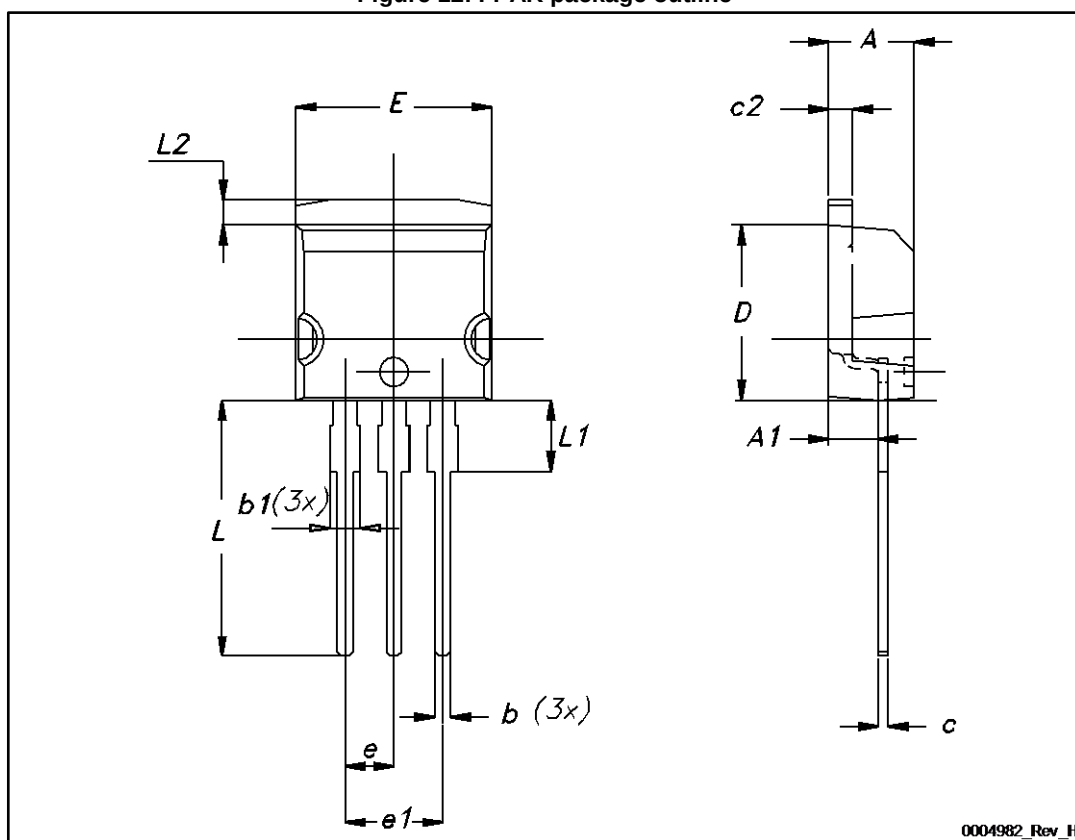


Table 6: TO-220AB package mechanical data

Ref.	Dimensions			
	Millimeters		Inches ⁽¹⁾	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.1732	0.1811
b	0.61	0.88	0.0240	0.0346
b1	1.14	1.70	0.0449	0.0669
c	0.48	0.70	0.0189	0.0276
D	15.25	15.75	0.6004	0.6201
D1	1.27 typ.		0.0500 typ.	
E	10.00	10.40	0.3937	0.4094
e	2.40	2.70	0.0945	0.1063
e1	4.95	5.15	0.1949	0.2028
F	1.23	1.32	0.0484	0.0520
H1	6.20	6.60	0.2441	0.2598
J1	2.40	2.72	0.0945	0.1071
L	13.00	14.00	0.5118	0.5512
L1	3.50	3.93	0.1378	0.1547
L20	16.40 typ.		0.6457 typ.	
L30	28.90 typ.		1.1378 typ.	
ØP	3.75	3.85	0.1476	0.1516
Q	2.65	2.95	0.1043	0.1161

Notes:⁽¹⁾Inch dimensions are for reference only.

2.3 I²PAK package information

Figure 12: I²PAK package outline

0004982_Rev_H

Table 7: I²PAK package mechanical data

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
A1	2.40	2.72	0.094	0.107
b	0.61	0.88	0.024	0.035
b1	1.14	1.70	0.044	0.067
c	0.49	0.70	0.019	0.028
c2	1.23	1.32	0.048	0.052
D	8.95	9.35	0.352	0.368
e	2.40	2.70	0.094	0.106
e1	4.95	5.15	0.195	0.203
E	10.00	10.40	0.394	0.409
L	13.00	14.00	0.512	0.551
L1	3.50	3.93	0.138	0.155
L2	1.27	1.40	0.050	0.055

3 Ordering information

Table 8: Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPS40SM120CR	PS40SM120CR	I ² PAK	1.49 g	50	Tube
STPS40SM120CTN	PS40SM120CTN	TO-220AB narrow leads	1.9 g	50	Tube
STPS40SM120CT	PS40SM120CT	TO-220AB	2.2 g	50	Tube

4 Revision history

Table 9: Document revision history

Date	Revision	Changes
02-Apr-2012	1	First issue.
04-Nov-2014	2	Added TO-220AB and TO-220FPAB package information.
11-Apr-2017	3	Updated Section 1: "Characteristics" and Section 1.1: "Characteristics (curves)" .

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